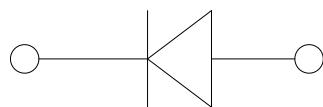
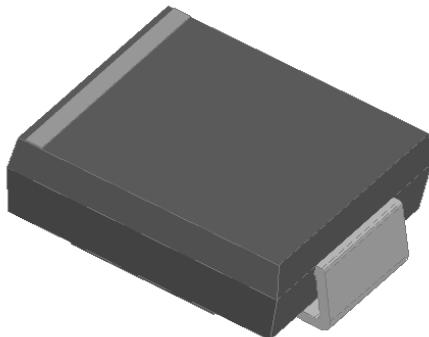


## Surface Mount Schottky Rectifier



### Features

- Guardring for overvoltage protection
- Low forward voltage drop, Low power losses
- High forward surge capability
- High frequency operation
- Low forward voltage drop, Low power losses
- Solder dip 260 °C max. 10 s, per JESD 22-B106

### Typical Applications

For use in low voltage high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

### Mechanical Data

- **Package:** DO-214AB (SMC)  
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** Color band denotes the cathode end

### ■ Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	SS34L	SS36L	SS310L
Device marking code			SS34L	SS36L	SS310L
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	V	40	60	100
Average Rectified Output Current @60Hz sine wave, Resistance load, Ta (FIG.1)	I <sub>o</sub>	A		3.0	
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave, 1 cycle, Ta=25°C	I <sub>FSM</sub>	A		60	
Storage Temperature	T <sub>Stg</sub>	°C		-55 ~+150	
Junction Temperature	T <sub>j</sub>	°C	-55 ~+125		-55 ~+150

### ■ Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	SS34L	SS36L	SS310L
Maximum instantaneous forward voltage drop per diode	V <sub>F</sub>	V	I <sub>FM</sub> =3.0A	0.45	0.5	0.6
Maximum DC reverse current at rated DC blocking voltage per diode	I <sub>R</sub>	mA	T <sub>a</sub> =25°C		0.5	
			T <sub>a</sub> =100°C		50	
Typical junction capacitance	C <sub>j</sub>	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C.	220	180	130

■ Thermal Characteristics ( $T_a=25^\circ\text{C}$  Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	SS34L	SS36L	SS310L
Thermal Resistance	Junction to ambient	$R_{\theta J-L}$	$^\circ\text{C}/\text{W}$		48 <sup>(1)</sup>	
	Junction to lead	$R_{\theta J-L}$	$^\circ\text{C}/\text{W}$		13 <sup>(1)</sup>	

■ Characteristics(Typical)

FIG.1: Io-Ta Curve

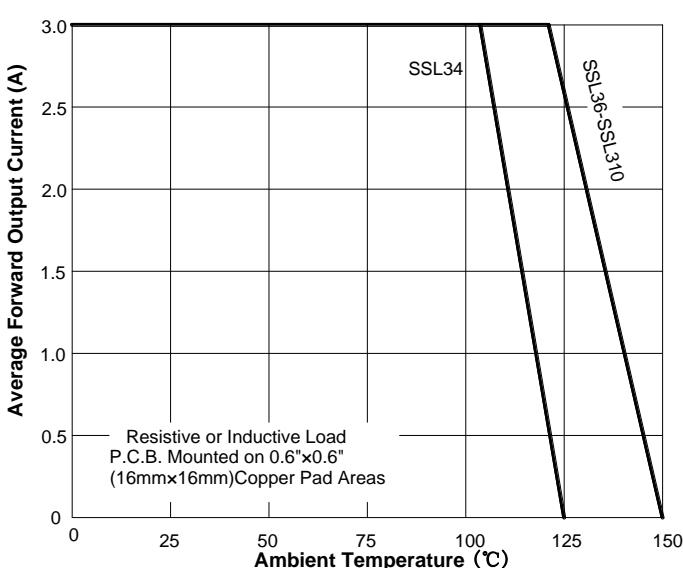


FIG.2: Forward Surge Current Capability

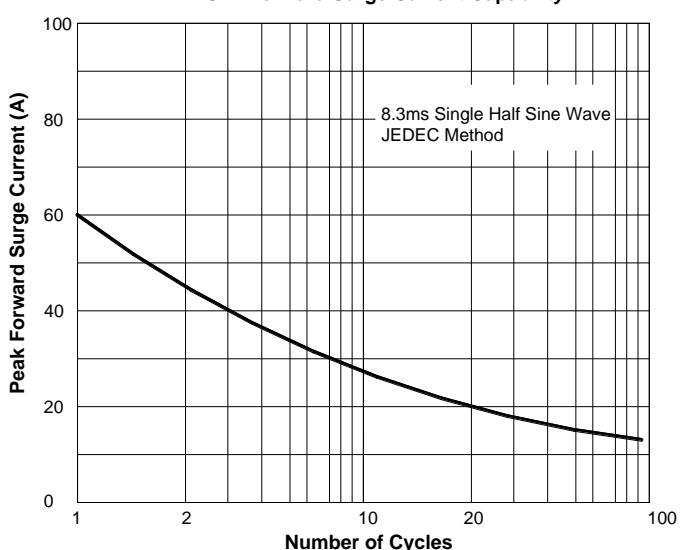


FIG.3: Forward Voltage

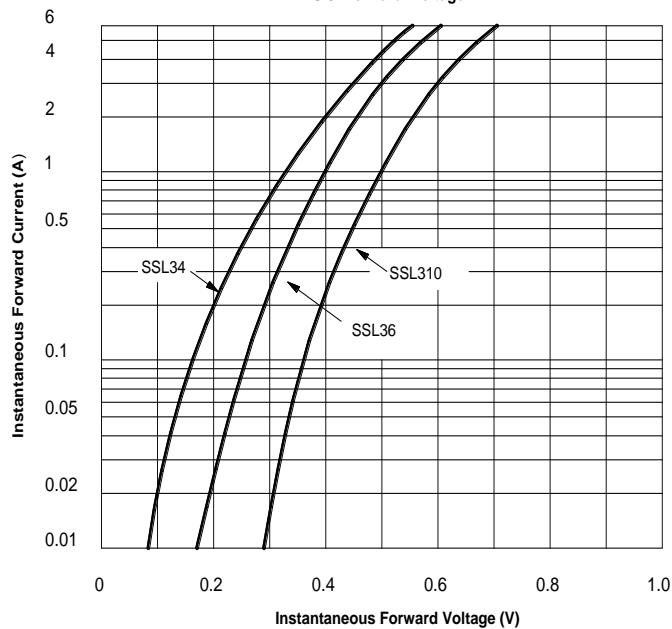
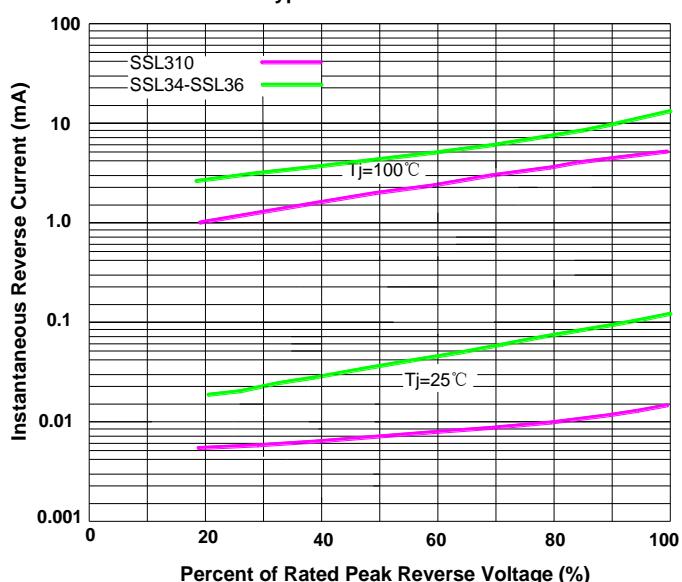


FIG.4: Typical Reverse Characteristics

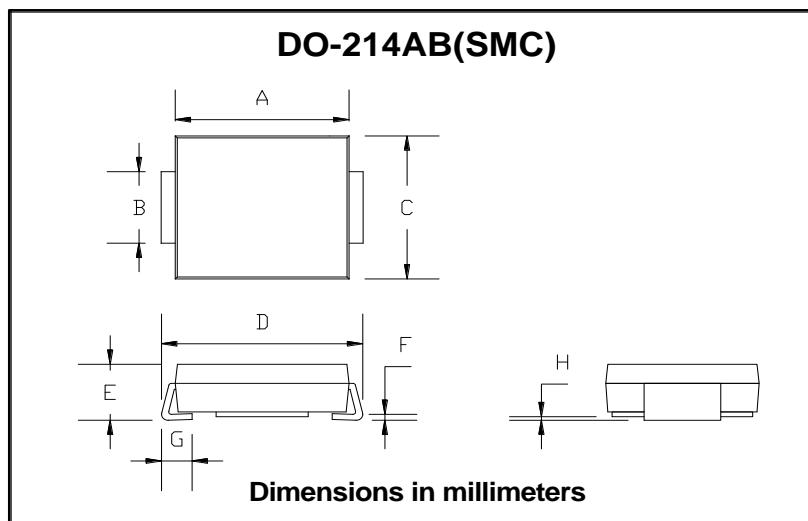




SEMI CONDUCTOR

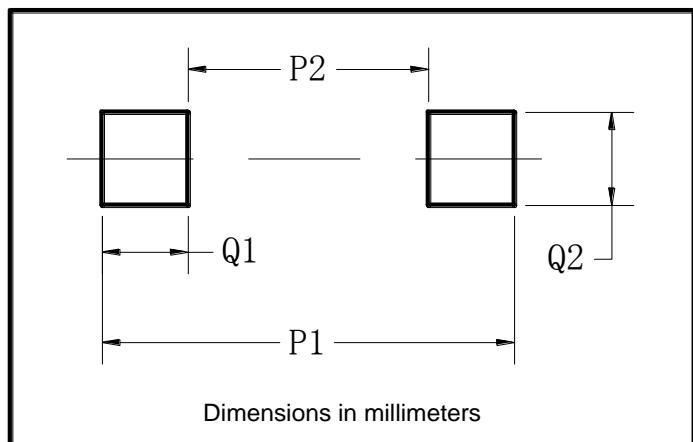
SS34L THRU SS310L(SMC)

### ■ Outline Dimensions



DO-214AB (SMC)		
Dim	Min	Max
A	6.60	7.11
B	2.85	3.27
C	5.59	6.22
D	7.75	8.13
E	1.99	2.61
F	0.15	0.31
G	0.76	1.52
H	0.10	0.20

### ■ Suggested pad layout



Dim	Typ
P1	9.9
P2	3.84
Q1	3.03
Q2	3.82